

12 A Three-quadrant triacs, insulated, high commutation, high temperature

Rev. 01 — 3 October 2007

Product data sheet

1. Product profile

1.1 General description

Passivated, new generation, high commutation triacs in an internally insulated TO-220 plastic package

1.2 Features

- Very high commutation performance
- Isolated mounting base
- High operating junction temperature

1.3 Applications

- Heating and cooking appliances
- High power motor control e.g. vacuum cleaners
- Solid state relays

1.4 Quick reference data

- V_{DRM} ≤ 600 V (BTA412Y-600B/C)
- V_{DRM} ≤ 800 V (BTA412Y-800B/C)
- I_{T(RMS)} ≤ 12 A

- High immunity to dV/dt
- 2500 V RMS isolation voltage
- Non-linear rectifier-fed motor loads
- Electronic thermostats for heating and cooling loads
- I_{GT} ≤ 50 mA (BTA412Y series B)
- I_{GT} \leq 35 mA (BTA412Y series C)
- I_{TSM} ≤ 140 A (t = 20 ms)



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SOT78D (TO-220)

2. Pinning information

| Table 1. | Pinning | | |
|----------|-------------------------|--------------------|--------|
| Pin | Description | Simplified outline | Symbol |
| 1 | main terminal 1 (T1) | | ν. |
| 2 | main terminal 2 (T2) | mb | T2-T1 |
| 3 | gate (G) | r 🔾 h | Sym051 |
| mb | mounting base; isolated | | |

3. Ordering information

Table 2.Ordering information

| Type number | Package | | | | | |
|--------------|---------|---|---------|--|--|--|
| | Name | Description | Version | | | |
| BTA412Y-600B | | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; | SOT78D | | | |
| BTA412Y-600C | | 3-lead TO-220 | | | | |
| BTA412Y-800B | | | | | | |
| BTA412Y-800C | | | | | | |

4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| | • | | | | |
|---------------------|--------------------------------------|---|--------------|-----|------------------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| V _{DRM} | repetitive peak off-state voltage | BTA412Y-600B; BTA412Y-600C | <u>[1]</u> _ | 600 | V |
| | | BTA412Y-800B; BTA412Y-800C | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{mb} \le 116 \text{ °C}$; see Figure 4 and 5 | - | 12 | А |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_j = 25 \text{ °C prior to}$ surge; see <u>Figure 2</u> and <u>3</u> | | | |
| | | t = 20 ms | - | 140 | А |
| | | t = 16.7 ms | - | 153 | А |
| l ² t | l ² t for fusing | t = 10 ms | - | 98 | A ² s |
| dl _T /dt | rate of rise of on-state current | $I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$ | - | 100 | A/μs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |

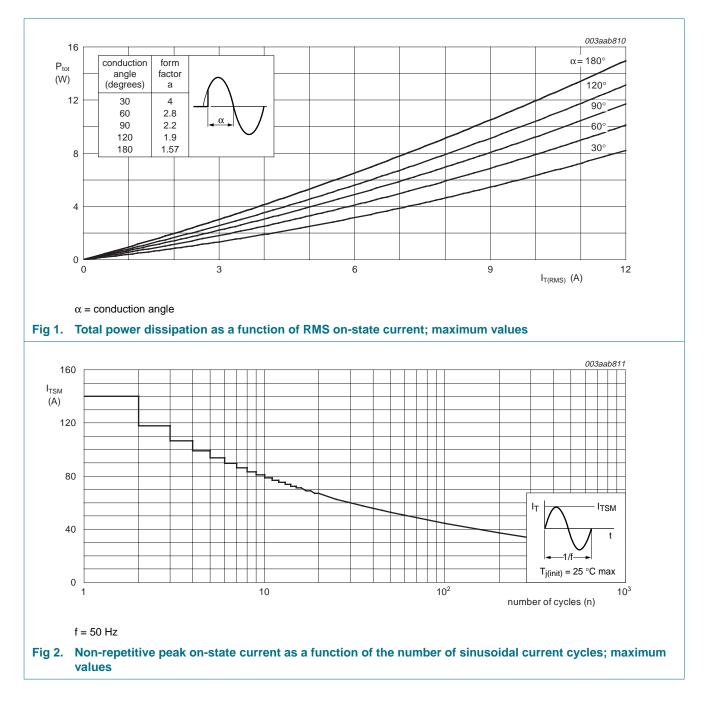
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Table 3.Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|--------------------|----------------------|-----------------------|-----|------|------|
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | +150 | °C |
| Tj | junction temperature | | - | 150 | °C |

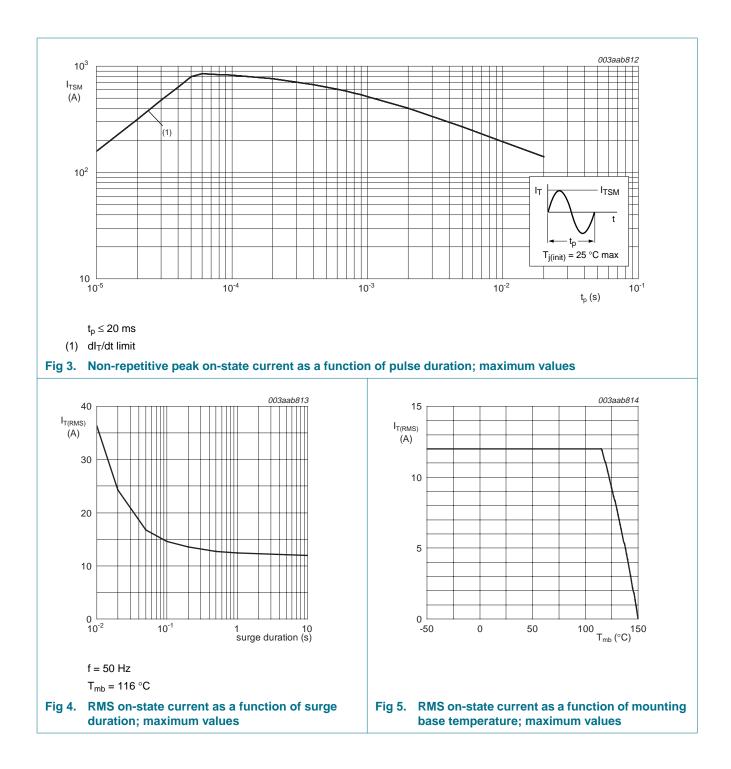
[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/μs.



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BTA412Y series B and C

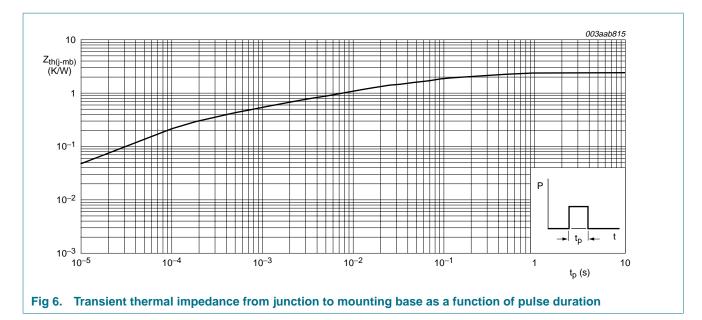
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Thermal characteristics 5.

| Table 4. | Thermal characteristics | | | | | |
|-----------------------|---|--------------------------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-mb)} | thermal resistance from junction to mounting base | full cycle; see Figure 6 | - | - | 2.1 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |



Isolation characteristics 6.

Isolation limiting values and characteristics Table 5.

 $T_h = 25 \circ C$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------------|-----------------------|--|-----|-----|------|------|
| V _{isol(RMS)} | RMS isolation voltage | from all three terminals to external heatsink; f = 50 Hz to 60 Hz; sinusoidal waveform; RH \leq 65 %; clean and dust free | - | - | 2500 | V |
| C _{isol} | isolation capacitance | from pin 2 to external heatsink; f = 1 MHz | - | 10 | - | pF |

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7. Static characteristics

Table 6. Static characteristics

 $T_i = 25 \circ C$ unless otherwise specified.

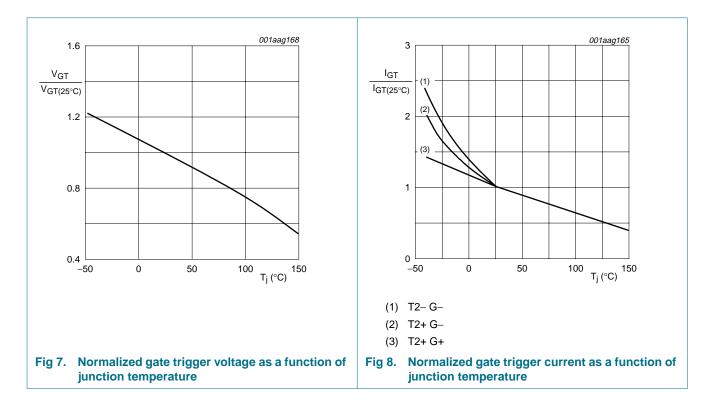
| Symbol | Parameter | Conditions | | BTA412Y-600B BTA412Y-800B | | | BTA412Y-600C BTA412Y-800C | | |
|-----------------|---------------------|---|------|------------------------------|-----|------|------------------------------|-----|----|
| | | | Min | Тур | Max | Min | Тур | Max | |
| I _{GT} | gate trigger | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 8}}{100000000000000000000000000000000000$ | | | | | | | |
| | current | T2+ G+ | 2 | - | 50 | 2 | - | 35 | mA |
| | | T2+ G- | 2 | - | 50 | 2 | - | 35 | mA |
| | | T2-G- | 2 | - | 50 | 2 | - | 35 | mA |
| IL | latching current | $V_D = 12 \text{ V}; \text{ I}_{GT} = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 10}{100000000000000000000000000000000$ | | | | | | | |
| | | T2+ G+ | - | - | 60 | - | - | 50 | mA |
| | | T2+ G- | - | - | 90 | - | - | 60 | mA |
| | | T2– G– | - | - | 60 | - | - | 50 | mA |
| I _H | holding current | $V_D = 12 \text{ V}; \text{ I}_{GT} = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 11}{\text{Figure } 11}$ | - | - | 60 | - | - | 35 | mA |
| V _T | on-state voltage | $I_T = 18 \text{ A}; \text{ see } \overline{\text{Figure 9}}$ | - | 1.3 | 1.5 | - | 1.3 | 1.5 | V |
| V _{GT} | gate trigger | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 7}}{100000000000000000000000000000000000$ | - | 0.8 | 1.5 | - | 0.8 | 1.5 | V |
| | voltage | $V_D = 400 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T}_j = 150 \ ^\circ\text{C}$ | 0.25 | 0.4 | - | 0.25 | 0.4 | - | V |
| I _D | off-state current | $V_D = V_{DRM(max)}; T_j = 125 \ ^{\circ}C$ | - | 0.1 | 0.5 | - | 0.1 | 0.5 | mA |
| | | $V_D = V_{DRM(max)}; T_j = 150 \ ^{\circ}C$ | - | 0.4 | 2 | - | 0.4 | 2 | mA |

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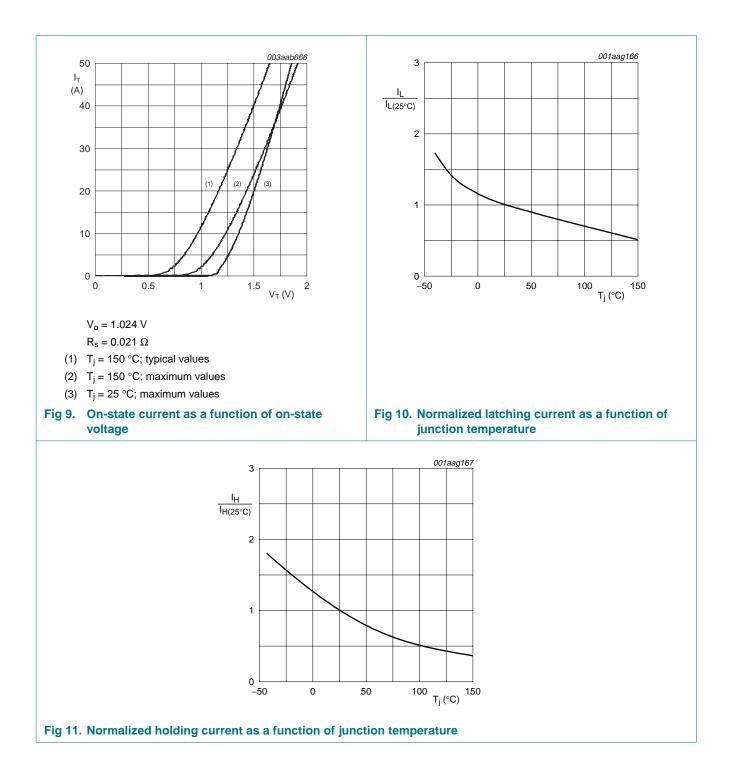
8. Dynamic characteristics

Table 7. Dynamic characteristics

| Symbol | Parameter | Conditions | BTA412Y-600B BTA412Y-800B | | | BTA412Y-600C BTA412Y-800C | | | Unit |
|---|---|---|------------------------------|-----|-----|------------------------------|-----|------|------|
| | | | Min | Тур | Max | Min | Тур | Max | |
| dV _D /dt rate of rise of off-state voltage | $V_{DM} = 0.67 \times V_{DRM(max)}$; T _j = 125 °C; exponential waveform; gate open circuit | 1000 | - | - | 500 | - | - | V/μs | |
| | voltage | $V_{DM} = 0.67 \times V_{DRM(max)}$; $T_j = 150 \text{ °C}$; exponential waveform; gate open circuit | 600 | - | - | 300 | - | - | V/µs |
| of comm | ••• | V_{DM} = 400 V; T _j = 125 °C; I _{T(RMS)} = 12 A; without snubber; gate open circuit | 20 | - | - | 15 | - | - | A/ms |
| | commutating current | V_{DM} = 400 V; T _j = 150 °C; I _{T(RMS)} = 12 A; without snubber; gate open circuit | 8 | - | - | 6 | - | - | A/ms |
| t _{gt} | gate-controlled turn-on time | I_{TM} = 20 A; V_D = $V_{DRM(max)}$; I_G = 0.1 A; dI _G /dt = 5 A/µs | - | 2 | - | - | 2 | - | μs |



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9. Package outline

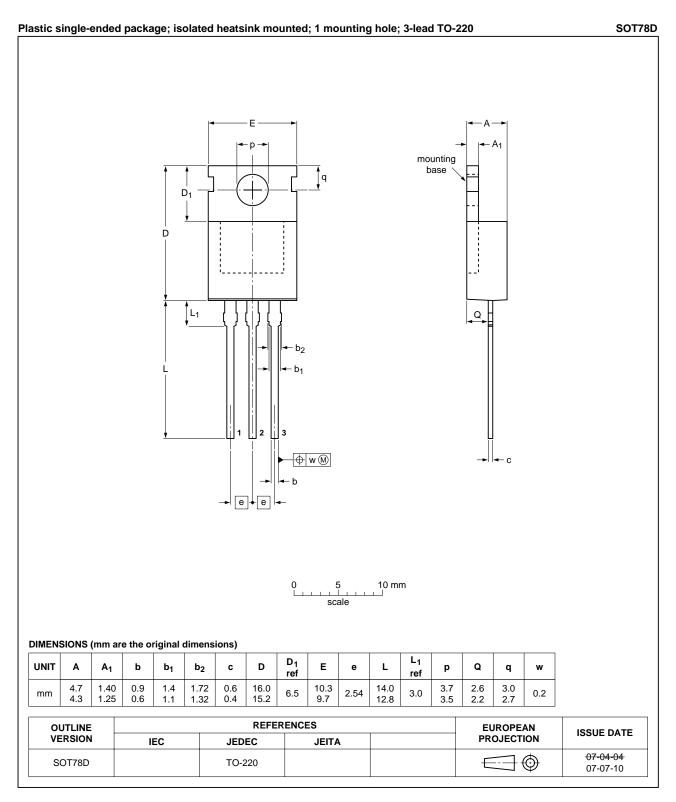


Fig 12. Package outline SOT78D (3-lead TO-220)

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10. Revision history

| Table 8. Revision hist | Revision history | | | | | |
|------------------------|------------------|--------------------|---------------|------------|--|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
| BTA412Y_SER_B_C_1 | 20071003 | Product data sheet | - | - | | |

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11. Legal information

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| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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